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Total Number of Pages: 02

B.Tech.  
PEE31102

3<sup>rd</sup> Semester Regular / Back Examination 2017-18

**ANALOG ELECTRONIC CIRCUITS**

**BRANCH: ELECTRICAL**

**Time: 3 Hours**

**Max Marks: 100**

**Q.CODE: B777**

**Answer Question No.1 and 2 which are compulsory and any four from the rest.**

**The figures in the right hand margin indicate marks.**

- Q1 Answer the following questions: *multiple type or dash fill up type* (2 x 10)**
- a) In a common emitter, unbypassed resistor provides
    - a) Voltage shunt feedback
    - b) Current series feedback
    - c) Negative voltage feedback
    - d) Positive current feedback
  - b) A CC amplifier has the highest
    - a) Voltage gain
    - b) Power gain
    - c) Current gain
    - d) Output impedance
  - c) The effective channel length of a MOSFET in a saturation decreases with increase in:
    - a) Gate voltage
    - b) Drain voltage
    - c) Source voltage
    - d) Body voltage
  - d) The ideal OP-AMP has the following characteristics:
    - a)  $R_i = \infty, A = \infty, R_o = 0$
    - b)  $R_i = 0, A = \infty, R_o = 0$
    - c)  $R_i = \infty, A = \infty, R_o = \infty$
    - d)  $R_i = 0, A = \infty, R_o = \infty$
  - e) If the feedback signal is returned to the input in series with the applied voltage, input impedance:
    - a) Decreases
    - b) Increases
    - c) Does not change
    - d) Becomes infinity
  - f) The maximum possible collector circuit efficiency of an ideal class power amplifier is:
    - a) 15%
    - b) 25%
    - c) 50%
    - d) 75%
  - g) The 'slew rate' of an operational amplifier indicates:
    - a) how fast its output current can change
    - b) how fast its output impedance can change
    - c) how fast its output power can change
    - d) how fast its output voltage can change
  - h) The large signal bandwidth of an op-amp is limited by:
    - a) loop gain
    - b) slew rate
    - c) output impedance
    - d) input frequency

- i) The feedback factor  $\beta$  at the frequency of oscillation of a Wien bridge oscillator is:
  - a) 3
  - b) 1/3
  - c) 1/29
  - d) 3/29
- j) The only drawback of using negative feedback in amplifiers is that it involves:
  - a) Gain sacrifice
  - b) Gain stability
  - c) Temperature sensitivity
  - d) Frequency dependence

**Q2 Answer the following questions: Short answer type (2 x 10)**

- a) Differentiate between BJT and FET.
  - b) Calculate  $\beta$  for two transistors for which  $\alpha = 0.99$  and  $0.98$ . For collector current of  $10 \text{ mA}$ , find the base current of each transistor.
  - c) Discuss about load line in BJT biasing circuit.
  - d) Among the various biasing circuits which one is commonly used and why.
  - e) Discuss about the series and parallel configurations of semiconductor diodes.
  - f) Whether the output of a CE configuration is in phase or out of phase with the input? Justify.
  - g) Differentiate between small-signal amplifier and large-signal amplifier.
  - h) What is the role of bypass capacitor in an amplifier circuit?
  - i) What are the advantages and disadvantages of negative feedback in an amplifier?
  - j) State and explain Barkhausen criteria of self oscillation.
- Q3**
- a) Explain the effect of coupling capacitor and bypass capacitor on the low frequency response of BJT amplifier. **(10)**
  - b) Compare the properties of CB, CE, CC configurations of BJT and explain which configuration is suitable for use in cascade amplifier stages. Justify your answer. **(5)**
- Q4**
- a) Determine the lower cut off frequency for the voltage divider bias BJT amplifier with  $C_S = 10\mu\text{F}$ ,  $C_E = 20\mu\text{F}$ ,  $R_S = 1\text{K}\Omega$ ,  $R_1 = 10\text{K}\Omega$ ,  $R_2 = 10\text{K}\Omega$ ,  $R_E = 2\text{K}\Omega$ ,  $R_C = 4\text{K}\Omega$ ,  $R_I = 2.2\text{K}\Omega$ ,  $\beta = 100$ ,  $r_o = \infty$ ,  $V_{CC} = 20\text{V}$ . **(10)**
  - b) Draw and explain the principle of operation of an emitter follower circuit. Justify its name. Derive expressions for its input and output impedances and the voltage gain **(5)**
- Q5**
- a) Describe the Hybrid parameters of a BJT and hence develop the Hybrid model and the simplified Hybrid model of the transistor. **(10)**
  - b) A BJT used in CE configuration with following parameters:  $R_L = 10\text{K}\Omega$ ,  $R_S = 2\text{K}\Omega$ ,  $h_{ie} = 1\text{K}\Omega$ ,  $h_{re} = 2 \times 10^{-4}$ ,  $h_{fe} = 50$  and  $h_{oe} = 25\mu$ . Calculate the values of  $A_i$ ,  $R_i$ ,  $A_v$ ,  $A_{vs}$  and  $Z_o$ . **(5)**
- Q6**
- a) For voltage series feedback amplifier topology, obtain expression for  $A_v$  and  $R_{if}$ . Also explain the principle of voltage amplifier used in feedback amplifiers. **(10)**
  - b) Sometimes an amplifier using negative feedback oscillates. Give reason for its oscillation. **(5)**
- Q7**
- a) Obtain an expression for frequency of oscillation in Colpitt's Oscillator. **(10)**
  - b) Explain the concept of positive feedback used in oscillator. **(5)**
- Q8**
- a) Draw the JFET common drain configuration (source-follower) circuit. Derive  $Z_i$ ,  $Z_o$ ,  $A_v$ , using small signal model. Write its characteristics. **(10)**
  - b) Explain the structure of depletion mode MOSFET. **(5)**
- Q9**
- a) What do you mean by power amplifier? Draw circuit diagram of push pull amplifier using a pair of complementary transistors and explain its operation. **(10)**
  - b) Explain comparator Circuit with neat diagram. **(5)**